Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L32	0	((second adj (switch switching)) and voltage and current and loss and hybrid and parallel and conduction and (control processor) and (on conducting) and (off non-conducting)).clm.	US-PGPUB	OR	ON	2008/01/24 18:20
L33	1	((second adj (switch switching)) and voltage and current and loss and parallel and conduction and (control processor) and (on conducting) and (off non-conducting)).clm.	US-PGPUB	OR	ON	2008/01/24 18:21
L34	2	((second adj (switch switching)) and voltage and current and loss and parallel and conduction and (control processor)).clm.	US-PGPUB	OR	ON	2008/01/24 18:22
L35	1	((second adj (switch switching)) and voltage and current and loss and parallel and conduction and (on conducting) and (off non-conducting)).clm.	US-PGPUB	OR	ON	2008/01/24 18:22

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	361/8.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:41
L2	1551	(mosfet (field-effect adj transistor) (field adj effect adj transistor) (metal adj oxide adj semiconductor adj (fet field)) (metal-oxide adj semiconductor adj (fet field))).ti. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:42
L3	1031	("mosfet" "mos transistor" "metal oxide semiconductor field effect transistor" "metal oxide semiconductor field-effect transistor" "metal-oxide semiconductor field effect transistor" "metal-oxide semiconductor field-effect transistor" "metal-oxide semiconductor field-effect transistor" "metal oxide semiconductor fet" "metal-oxide semiconductor fet").ti. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:45
L4	49	("mosfet" "mos transistor" "metal oxide semiconductor field effect transistor" "metal oxide semiconductor field-effect transistor" "metal-oxide semiconductor field effect transistor" "metal-oxide semiconductor field-effect transistor" "metal-oxide semiconductor field-effect transistor" "metal oxide semiconductor fet" "metal-oxide semiconductor fet").ti. and switch.ti. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:46
L5	7	361/2.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:47

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L6	1	361/8.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:47
L7	0	361/13.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2008/01/24 17:48
L8	0	(parallel with (second adj igbt) with mosfet) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:48
L9	0	(parallel with (second adj igbt) same mosfet) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:48
L10	24	(parallel with igbt same mosfet) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:49
L11	14	307/112.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:49
L12	1	307/113.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:50

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L13	9	307/115.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:50
L14	4	307/125.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:51
L15	4	307/131.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:52
L16	0	307/141.4.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:52
L17		307/141.8.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:53
L18	1	307/143.ccls. and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:53
L19	8	(igbt with diode with mosfet with parallel) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:54

L20	2	(switch with (cryogenic adj (cool cooling))) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:54
L22	0	(cryogenic\$ adj (cool cooled cooling)) same (switch adj loss) same (conduction adj loss) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:55
L23	0	(cryogenic\$ adj (cool cooled cooling)) same (switch adj loss) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2008/01/24 17:56
L24	0	(cryogenic\$ adj (cool cooled cooling)) same (switch adj time) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:56
L25	0	(cryogenic\$ adj (cool cooled cooling)) same ((switch siwtching) adj (time loss)) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:56
L26	37	((switch switching) adj (time loss)) same (conduction adj loss) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:57
L27		(hybrid adj switch) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:57

L28	3	(hybrid adj switch) and switching and conduction and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:57
L29	19	((reduce adj (conduction switching losses)) same (switch switching) same (time duration) same (order sequence)) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:58
L30	1	((reduce adj (conduction switching losses)) same (switch switching) same (predetermined adj (time duration)) same (order sequence)) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 17:58
L31	1	(((reduce adj losses) (reduce adj (conduction switching) adj losses)) same (switch switching) same (predetermined adj (time duration)) same (order sequence)) and @pd>="20070815"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/01/24 18:00

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